EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L3	73565	(TFT (thin near5 film near5 transistor))	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 12:27
L4	4781	3 and ((first near5 gate) same (second near5 gate) same (source and drain))	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 12:28
L5	3276	4 and pixel	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 12:23
L6	51	5 and (photodetect$3 (photo near5 detect$3))	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 12:29
L7	47386	(TFT (thin near5 film near5 transistor))	FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 12:27
L8	807	7 and ((first near5 gate) and (second near5 gate) and (source and drain))	FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 12:28
L9	6	8 and (photodetect$3 (photo near5 detect$3))	FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 12:29

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	73565	(TFT (thin near5 film near5 transistor))	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 11:41
L2	801	1 and ((photo near5 detect$3) photodetecting)	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 11:41
L3	394	2 and (source and drain)	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 11:42
L4	213	3 and (first near5 gate)	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 11:10
L5	186	3 and (second near5 gate)	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 11:10
L6	143	5 and (insulat$3 dielectric)	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 11:10
L7	131	6 and pixel	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 11:10
L8	47386	(TFT (thin near5 film near5 transistor))	FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 11:41
L9	59	8 and ((photo near5 detect$3) photodetecting)	FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 11:42
L10	18	9 and (source and drain)	FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 11:42